

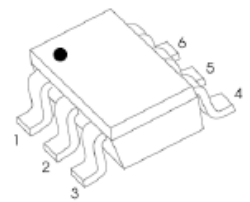
Dual Bias Resistor Transistors

NPN Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. In the MMUN5211DW series, two BRT devices are housed in the SOT-363 package which is ideal for low power surface mount applications where board space is at a premium.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- We declare that the material of product compliance with RoHS requirements.

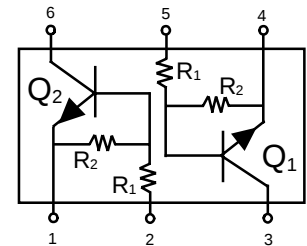
MMUN5211DW Series



SOT-363

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted, common for Q₁ and Q₂)

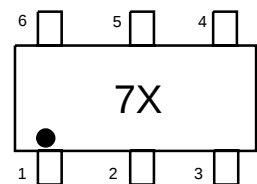
Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current	I _C	100	mAdc



THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C	P _D	187 (Note 1.) 256 (Note 2.)	mW
Derate above 25°C		1.5 (Note 1.) 2.0 (Note 2.)	mW/°C
Thermal Resistance – Junction-to-Ambient	R _{θJA}	670 (Note 1.) 490 (Note 2.)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C	P _D	250 (Note 1.) 385 (Note 2.)	mW
Derate above 25°C		2.0 (Note 1.) 3.0 (Note 2.)	mW/°C
Thermal Resistance – Junction-to-Ambient	R _{θJA}	493 (Note 1.) 325 (Note 2.)	°C/W
Thermal Resistance – Junction-to-Lead	R _{θJL}	188 (Note 1.) 208 (Note 2.)	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

MARKING DIAGRAM



7X = Device Marking
(See Page 2)

DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

DEVICE MARKING , RESISTOR VALUES AND ORDERING INFORMATION

Device	Package	Marking	R1(K)	R2(K)	Shipping
MMUN5211DW	SOT-363	7A	10	10	3000/Tape&Reel
MMUN5212DW	SOT-363	7B	22	22	3000/Tape&Reel
MMUN5213DW	SOT-363	7C	47	47	3000/Tape&Reel
MMUN5214DW	SOT-363	7D	10	47	3000/Tape&Reel
MMUN5215DW	SOT-363	7E	10	∞	3000/Tape&Reel
MMUN5216DW	SOT-363	7F	4.7	∞	3000/Tape&Reel
MMUN5230DW	SOT-363	7G	1	1	3000/Tape&Reel
MMUN5231DW	SOT-363	7H	2.2	2.2	3000/Tape&Reel
MMUN5232DW	SOT-363	7J	4.7	4.7	3000/Tape&Reel
MMUN5233DW	SOT-363	7K	4.7	47	3000/Tape&Reel
MMUN5234DW	SOT-363	7L	22	47	3000/Tape&Reel
MMUN5235DW	SOT-363	7M	2.2	47	3000/Tape&Reel
MMUN5238DW	SOT-363	7Q	2.2	∞	3000/Tape&Reel
MMUN5241DW	SOT-363	7T	100	∞	3000/Tape&Reel

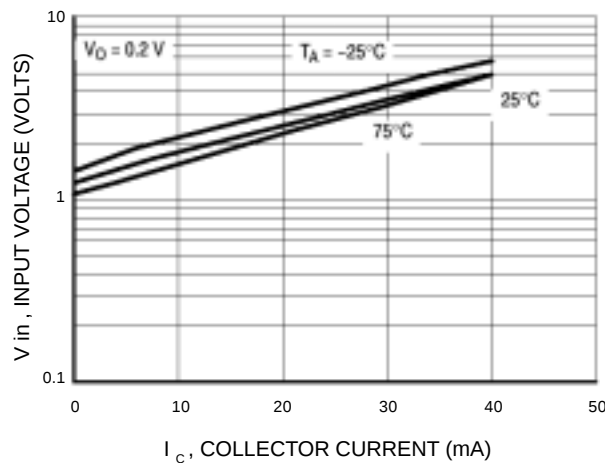
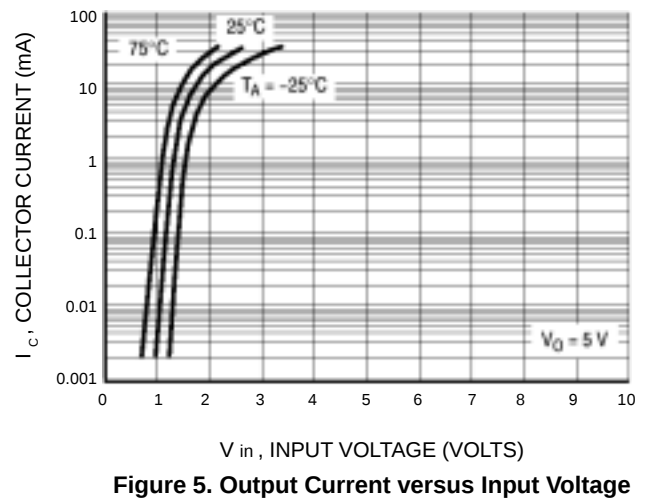
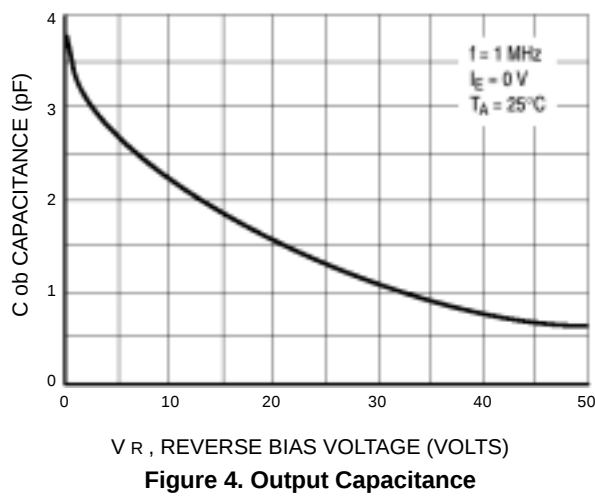
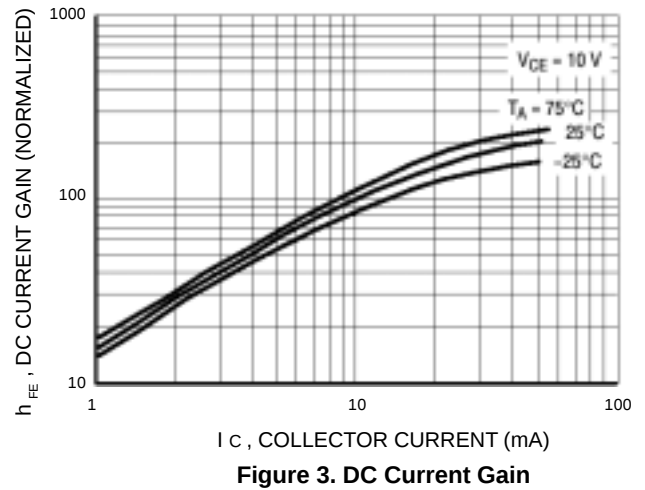
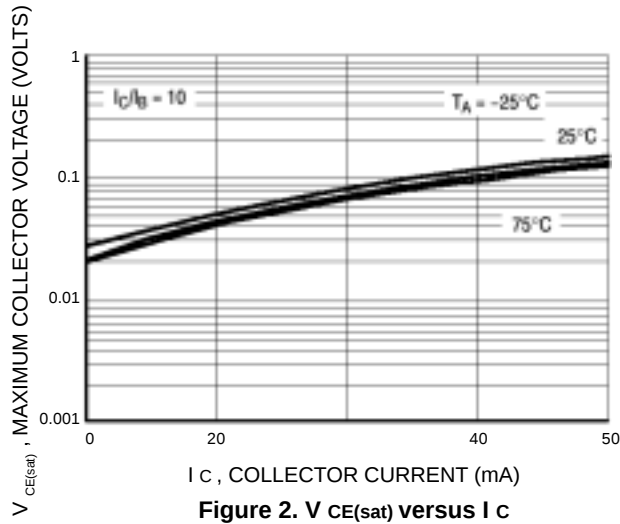
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, common for Q₁ and Q₂),(Continued)

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 10\text{ V}$, $I_C = 5\text{ mA}$				
MMUN5211DW	h_{FE}	35	-	-
MMUN5212DW	h_{FE}	60	-	-
MMUN5213DW	h_{FE}	80	-	-
MMUN5214DW	h_{FE}	80	-	-
MMUN5215DW	h_{FE}	160	-	-
MMUN5216DW	h_{FE}	160	-	-
MMUN5230DW	h_{FE}	3	-	-
MMUN5231DW	h_{FE}	8	-	-
MMUN5232DW	h_{FE}	15	-	-
MMUN5233DW	h_{FE}	80	-	-
MMUN5234DW	h_{FE}	80	-	-
MMUN5235DW	h_{FE}	80	-	-
MMUN5238DW	h_{FE}	160	-	-
MMUN5241DW	h_{FE}	160	-	-
Collector Base Cutoff Current at $V_{CB} = 50\text{ V}$	I_{CBO}	-	100	nA
Collector Emitter Cutoff Current at $V_{CE} = 50\text{ V}$	I_{CEO}	-	500	nA
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$				
MMUN5211DW	I_{EBO}	-	0.5	mA
MMUN5212DW	I_{EBO}	-	0.2	mA
MMUN5213DW	I_{EBO}	-	0.1	mA
MMUN5214DW	I_{EBO}	-	0.2	mA
MMUN5215DW	I_{EBO}	-	0.9	mA
MMUN5216DW	I_{EBO}	-	1.9	mA
MMUN5230DW	I_{EBO}	-	4.3	mA
MMUN5231DW	I_{EBO}	-	2.3	mA
MMUN5232DW	I_{EBO}	-	1.5	mA
MMUN5233DW	I_{EBO}	-	0.18	mA
MMUN5234DW	I_{EBO}	-	0.13	mA
MMUN5235DW	I_{EBO}	-	0.2	mA
MMUN5238DW	I_{EBO}	-	4	mA
MMUN5241DW	I_{EBO}	-	0.1	mA
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	50	-	V
Collector Emitter Breakdown Voltage at $I_C = 2\text{ mA}$	$V_{(BR)CEO}$	50	-	V
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$, $I_B = 0.3\text{ mA}$	V_{CEsat}	-	0.25	V
at $I_C = 10\text{ mA}$, $I_B = 5\text{ mA}$	V_{CEsat}	-	0.25	V
MMUN5230DW	V_{CEsat}	-	0.25	V
MMUN5231DW	V_{CEsat}	-	0.25	V
MMUN5215DW	V_{CEsat}	-	0.25	V
MMUN5216DW	V_{CEsat}	-	0.25	V
MMUN5232DW	V_{CEsat}	-	0.25	V
MMUN5233DW	V_{CEsat}	-	0.25	V
MMUN5234DW	V_{CEsat}	-	0.25	V
MMUN5235DW	V_{CEsat}	-	0.25	V
MMUN5238DW	V_{CEsat}	-	0.25	V

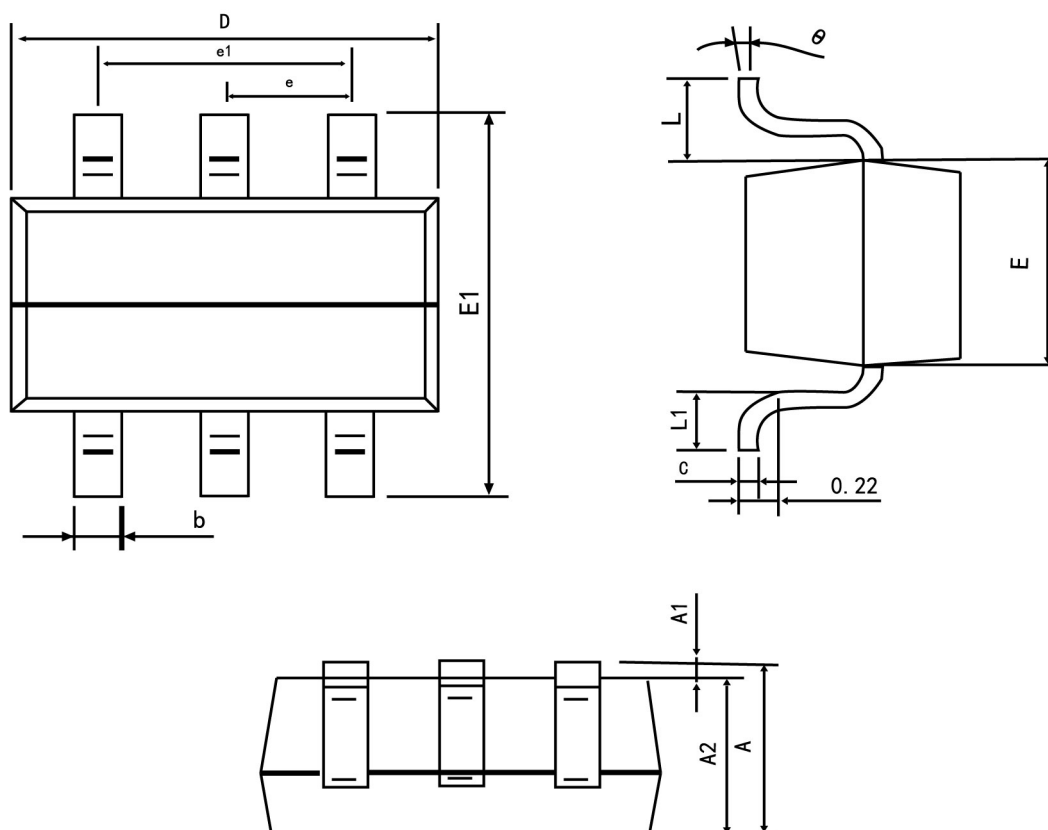
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted, common for Q₁ and Q₂.) (Continued)

Parameter	Symbol	Min.	Max.	Unit
Output Voltage (on) at $V_{CC} = 5\text{ V}$, $V_B = 2.5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN5211DW V_{OL}	-	0.2	V
	MMUN5212DW V_{OL}	-	0.2	V
	MMUN5214DW V_{OL}	-	0.2	V
	MMUN5215DW V_{OL}	-	0.2	V
	MMUN5216DW V_{OL}	-	0.2	V
	MMUN5230DW V_{OL}	-	0.2	V
	MMUN5231DW V_{OL}	-	0.2	V
	MMUN5232DW V_{OL}	-	0.2	V
	MMUN5233DW V_{OL}	-	0.2	V
	MMUN5234DW V_{OL}	-	0.2	V
	MMUN5235DW V_{OL}	-	0.2	V
at $V_{CC} = 5\text{ V}$, $V_B = 3.5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN5238DW V_{OL}	-	0.2	V
at $V_{CC} = 5\text{ V}$, $V_B = 5\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN5213DW V_{OL}	-	0.2	V
	MMUN5241DW V_{OL}	-	0.2	V
Output Voltage (off) at $V_{CC} = 5\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1\text{ K}\Omega$	V_{OH}	4.9	-	V
at $V_{CC} = 5\text{ V}$, $V_B = 0.05\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN5230DW V_{OH}	4.9	-	V
at $V_{CC} = 5\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1\text{ K}\Omega$	MMUN5215DW V_{OH}	4.9	-	V
	MMUN5216DW V_{OH}	4.9	-	V
	MMUN5233DW V_{OH}	4.9	-	V
	MMUN5238DW V_{OH}	4.9	-	V
Input Resistor	MMUN5211DW R1	7	13	K Ω
	MMUN5212DW R1	15.4	28.6	K Ω
	MMUN5213DW R1	32.9	61.1	K Ω
	MMUN5214DW R1	7	13	K Ω
	MMUN5215DW R1	7	13	K Ω
	MMUN5216DW R1	3.3	6.1	K Ω
	MMUN5230DW R1	0.7	1.3	K Ω
	MMUN5231DW R1	1.5	2.9	K Ω
	MMUN5232DW R1	3.3	6.1	K Ω
	MMUN5233DW R1	3.3	6.1	K Ω
	MMUN5234DW R1	15.4	28.6	K Ω
	MMUN5235DW R1	1.54	2.86	K Ω
	MMUN5238DW R1	1.54	2.88	K Ω
	MMUN5241DW R1	70	130	K Ω
Resistor Ratio	MMUN5211DW/MMUN5212DW/MMUN5213DW R1/R2	0.8	1.2	-
	MMUN5214DW R1/R2	0.17	0.25	-
	MMUN5215DW/MMUN5216DW/MMUN5238DW R1/R2	-	-	-
	MMUN5241DW R1/R2	-	-	-
	MMUN5230DW/MMUN5231DW/MMUN5232DW R1/R2	0.8	1.2	-
	MMUN5233DW R1/R2	0.055	0.185	-
	MMUN5234DW R1/R2	0.38	0.56	-
	MMUN5235DW R1/R2	0.038	0.056	-

TYPICAL ELECTRICAL CHARACTERISTICS – MMUN5211DW



SOT-363 Package Outline Dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°